

LMP2011 Single/LMP2012 Dual High Precision, Rail-to-Rail Output Operational Amplifier

General Description

National Semiconductor

The LMP201x series are the first members of National's new LMP[™] precision amplifier family. The LMP201X series offers unprecedented accuracy and stability in space-saving miniature packaging while also being offered at an affordable price. This device utilizes patented techniques to measure and continually correct the input offset error voltage. The result is an amplifier which is ultra stable over time and temperature. It has excellent CMRR and PSRR ratings, and does not exhibit the familiar 1/f voltage and current noise increase that plagues traditional amplifiers. The combination of the LM-P201X characteristics makes it a good choice for transducer amplifiers, high gain configurations, ADC buffer amplifiers, DAC I-V conversion, and any other 2.7V-5V application requiring precision and long term stability.

Other useful benefits of the LMP201X are rail-to-rail output, a low supply current of 930 µA, and wide gain-bandwidth product of 3 MHz. These extremely versatile features found in the LMP201X provide high performance and ease of use.

Features

(For $V_s = 5V$, Typical unless otherwise noted)

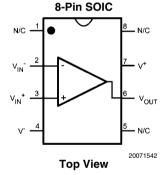
- 60 µV Low guaranteed VOS over temperature 35nV/√Hz Low noise with no 1/f High CMRR 130 dB High PSRR 120 dB High A_{VOL} 130 dB 3MHz Wide gain-bandwidth product High slew rate 4V/µs Low supply current 930µA -30mV
- Rail-to-rail output
- -No external capacitors required

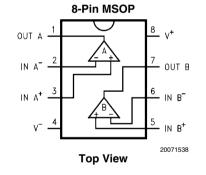
Applications

- Precision instrumentation amplifiers
- Thermocouple amplifiers
- Strain gauge bridge amplifier

5-Pin SOT23 5 ν_{ουτ} $V_{|N|}$ IN 20071502 **Top View**

Connection Diagrams





Ordering Information

| Package | Part Number | Temperature Range | Package Marking | Transport Media | NSC Drawing |
|--------------|-------------|----------------------|-----------------|--------------------------|-------------|
| 5-Pin SOT23 | LMP2011MF | | AN1A | 1k Units Tape and Reel | MF05A |
| 5-FIII 30123 | LMP2011MFX | | ANTA | 3k Units Tape and Reel | MIF03A |
| 8-Pin MSOP | LMP2012MM | | AP1A | 1k Units Tape and Reel | MUA08A |
| 0-FIII MISOF | LMP2012MMX | –40°C to 125°C | AFTA | 3.5k Units Tape and Reel | MUAU6A |
| | LMP2011MA | -40 0 10 125 0 | LMP2011MA | 95 Units/Rail | |
| | LMP2011MAX | | LIVIP2011IMA | 2.5k Units Tape and Reel | MOOA |
| 8-Pin SOIC | LMP2012MA | | | 95 Units/Rail | M08A |
| 1 | LMP2012MAX | | LMP2012MA | 2.5k Units Tape and Reel | |

If Military/Aerospace specified devices are required, please contact the National Semiconductor Sales Office/ Distributors for availability and specifications.

| ESD Tolerance | |
|--------------------------------------|--|
| Human Body Model | 2000V |
| Machine Model | 200V |
| Supply Voltage | 5.8V |
| Common-Mode Input Voltage | $-0.3 \leq V_{\rm CM} \leq V_{\rm CC} + 0.3 V$ |
| Lead Temperature (soldering 10 sec.) | +300°C |

| Differential Input Voltage | ±Supply Voltage |
|-----------------------------|-----------------|
| Current at Input Pin | 30 mA |
| Current at Output Pin | 30 mA |
| Current at Power Supply Pin | 50 mA |

Operating Ratings (Note 1)

| Supply Voltage | 2.7V to 5.25V |
|-----------------------------|----------------|
| Storage Temperature Range | –65°C to 150°C |
| Operating Temperature Range | –40°C to 125°C |

2.7V DC Electrical Characteristics Unless otherwise specified, all limits guaranteed for $T_J = 25^{\circ}$ C, V⁺ = 2.7V, V⁻ = 0V, V_{CM} = 1.35V, V_O = 1.35V and R_L > 1 MΩ. **Boldface** limits apply at the temperature extremes.

| Symbol | Parameter | Conditions | Min (Note 3) | Typ (Note 2) | Max (Note 3) | Units |
|-------------------|--------------------------------|--|-----------------------|-----------------|-----------------------|----------|
| V _{os} | Input Offset Voltage | | | 0.8 | 25 | |
| 00 | (LMP2011 only) | | | | 60 | |
| | Input Offset Voltage | | | 0.8 | 36 | - μV |
| (L | (LMP2012 only) | | | | 60 | |
| | Offset Calibration Time | | | 0.5 | 10 12 | ms |
| TCV _{OS} | Input Offset Voltage | | | 0.015 | | μV/°C |
| | Long-Term Offset Drift | | | 0.006 | | μV/month |
| | Lifetime V _{OS} Drift | | | 2.5 | | μV |
| I _{IN} | Input Current | | | -3 | | рА |
| l _{os} | Input Offset Current | | | 6 | | рА |
| R _{IND} | Input Differential Resistance | | | 9 | | MΩ |
| CMRR | Common Mode Rejection Ratio | –0.3 ≤ V _{CM} ≤ 0.9V | 95 | 130 | | dB |
| | | $0 \le V_{CM} \le 0.9V$ | 90 | | | |
| PSRR | Power Supply Rejection Ratio | | 95 | 120 | | dB |
| | | | 90 | | | |
| A _{VOL} | Open Loop Voltage Gain | $R_L = 10 \text{ k}\Omega$ | 95 | 130 | | |
| | | | 90 | | | dB |
| | | $R_L = 2 k\Omega$ | 90 | 124 | | |
| <u></u> | Output Swing | | 85 | 0.00 | | |
| Vo | Output Swing (LMP2011 only) | $R_L = 10 \text{ k}\Omega \text{ to } 1.35\text{V}$ | 2.665 2.655 | 2.68 | | |
| | | $V_{IN}(diff) = \pm 0.5V$ | 2.000 | 0.033 | 0.060 | - v |
| | | | | | 0.075 | |
| | | $R_1 = 2 k\Omega$ to 1.35V | 2.630 | 2.65 | | |
| | | $V_{IN}(diff) = \pm 0.5V$ | 2.615 | | | - v |
| | | | | 0.061 | 0.085 0.105 | V |
| | Output Swing | $R_L = 10 \text{ k}\Omega \text{ to } 1.35 \text{V}$ | 2.64 | 2.68 | | |
| | (LMP2012 only) | $V_{IN}(diff) = \pm 0.5V$ | 2.63 | | | v |
| | | | | 0.033 | 0.060 0.075 | |
| | | R ₁ = 2 kΩ to 1.35V | 2.615 | 2.65 | 0.075 | |
| | | $R_{L} = 2 \text{ kg to 1.35V}$ $V_{IN}(\text{diff}) = \pm 0.5\text{V}$ | 2.013 2.6 | 2.00 | | |
| | | | | 0.061 | 0.085 | - V |
| | | | | | 0.105 | |

| Symbol | Parameter | Conditions | Min (Note 3) | Typ (Note 2) | Max (Note 3) | Units |
|--|--|--|---|---|---|--|
| 0 | Output Current | Sourcing, V _O = 0V | 5 | 12 | (/ | |
| 0 | | $V_{IN}(diff) = \pm 0.5V$ | 3 | | | |
| | | Sinking, $V_0 = 5V$ | 5 | 18 | | mA |
| | | $V_{IN}(diff) = \pm 0.5V$ | 3 | _ | | |
| S | Supply Current per Channel | | | 0.919 | 1.20 1.50 | mA |
| 2.7V MΩ. Bol Symbol | AC Electrical Charac dface limits apply at the temperatu Parameter | T _J = 25°C, V+ = 25°C | Min | Тур | Max | nd R _L > 1 |
| | | | (Note 3) | (Note 2) | (Note 3) | |
| GBW | Gain-Bandwidth Product | | | 3 | | MHz |
| SR | Slew Rate | | | 4 | | V/µs |
|) m | Phase Margin | | | 60 | | Deg |
| G _m | Gain Margin | | | -14 | | dB |
| ə _n | Input-Referred Voltage Noise | | | 35 | | nV/√Hz |
| n | Input-Referred Current Noise | | | | | pA/√Hz |
| ə _n p-p | Input-Referred Voltage Noise | $R_{\rm S}$ = 100 Ω , DC to 10 Hz | | 850 | | nV _{pp} |
| rec | Input Overload Recovery Time | | | 50 | | ms |
| V⁻ = 0V, | C Electrical Characte $V_{CM} = 2.5V, V_0 = 2.5V \text{ and } R_L >$ | 1MΩ. Boldface limits apply at the | e temperature extre | emes. | | |
| 5V D V ⁻ = 0V, Symbol | C Electrical Characte $V_{CM} = 2.5V, V_0 = 2.5V \text{ and } R_L >$ Parameter | eristics Unless otherwise sp 1MΩ. Boldface limits apply at the Conditions | e temperature extre Min | emes. Typ | Мах | V+ = 5V, Units |
| V ⁻ = 0V, Symbol | $V_{CM} = 2.5V, V_{O} = 2.5V \text{ and } R_{L} >$ Parameter | 1MΩ. Boldface limits apply at the | e temperature extre | emes. | | |
| V ⁻ = 0V, Symbol | V $_{CM}$ = 2.5V, V $_{O}$ = 2.5V and R $_{L}$ > | 1MΩ. Boldface limits apply at the | e temperature extre Min | emes. Typ (Note 2) | Max (Note 3) | Units |
| V ⁻ = 0V, Symbol | V _{CM} = 2.5V, V _O = 2.5V and R _L > Parameter Input Offset Voltage | 1MΩ. Boldface limits apply at the | e temperature extre Min | emes. Typ (Note 2) | Max (Note 3) 25 | |
| V ⁻ = 0V, Symbol | V _{CM} = 2.5V, V _O = 2.5V and R _L > Parameter Input Offset Voltage (LMP2011 only) Input Offset Voltage (LMP2012 only) | 1MΩ. Boldface limits apply at the | e temperature extre Min | emes. Typ (Note 2) 0.12 | Max (Note 3) 25 60 36 60 | Units |
| V ⁻ = 0V, Symbol | V _{CM} = 2.5V, V _O = 2.5V and R _L > Parameter Input Offset Voltage (LMP2011 only) Input Offset Voltage | 1MΩ. Boldface limits apply at the | e temperature extre Min | emes. Typ (Note 2) 0.12 | Max (Note 3) 25 60 36 | Units |
| V- = 0V, Symbol | V _{CM} = 2.5V, V _O = 2.5V and R _L > Parameter Input Offset Voltage (LMP2011 only) Input Offset Voltage (LMP2012 only) | 1MΩ. Boldface limits apply at the | e temperature extre Min | emes. Typ (Note 2) 0.12 0.12 | Max (Note 3) 25 60 36 60 10 | Units µV |
| V- = 0V, Symbol | V _{CM} = 2.5V, V _O = 2.5V and R _L > Parameter Input Offset Voltage (LMP2011 only) Input Offset Voltage (LMP2012 only) Offset Calibration Time | 1MΩ. Boldface limits apply at the | e temperature extre Min | emes. Typ (Note 2) 0.12 0.12 0.5 | Max (Note 3) 25 60 36 60 10 | Units μV ms μV/°C |
| V- = 0V, Symbol | V _{CM} = 2.5V, V _O = 2.5V and R _L > Parameter Input Offset Voltage (LMP2011 only) Input Offset Voltage (LMP2012 only) Offset Calibration Time Input Offset Voltage | 1MΩ. Boldface limits apply at the | e temperature extre Min | emes. Typ (Note 2) 0.12 0.12 0.5 0.015 | Max (Note 3) 25 60 36 60 10 | Units μV ms μV/°C |
| V- = 0V, Symbol V _{os} | V _{CM} = 2.5V, V _O = 2.5V and R _L > Parameter Input Offset Voltage (LMP2011 only) Input Offset Voltage (LMP2012 only) Offset Calibration Time Input Offset Voltage Long-Term Offset Drift | 1MΩ. Boldface limits apply at the | e temperature extre Min | emes. Typ (Note 2) 0.12 0.12 0.5 0.015 0.006 | Max (Note 3) 25 60 36 60 10 | Units μV ms μV/°C μV/month |
| V- = 0V, Symbol V _{OS} TCV _{OS} | V _{CM} = 2.5V, V _O = 2.5V and R _L > Parameter Input Offset Voltage (LMP2011 only) Input Offset Voltage (LMP2012 only) Offset Calibration Time Input Offset Voltage Long-Term Offset Drift Lifetime V _{OS} Drift | 1MΩ. Boldface limits apply at the | e temperature extre Min | Typ (Note 2) 0.12 0.12 0.12 0.12 0.12 0.5 0.0015 0.006 2.5 | Max (Note 3) 25 60 36 60 10 | Units μV ms μV/°C μV/montr μV |
| V- = 0V, Symbol / _{OS} FCV _{OS} IN OS | V _{CM} = 2.5V, V _O = 2.5V and R _L > Parameter Input Offset Voltage (LMP2011 only) Input Offset Voltage (LMP2012 only) Offset Calibration Time Input Offset Voltage Long-Term Offset Drift Lifetime V _{OS} Drift Input Current | 1MΩ. Boldface limits apply at the | e temperature extre Min | emes. Typ (Note 2) 0.12 0.12 0.5 0.015 0.006 2.5 -3 | Max (Note 3) 25 60 36 60 10 | Units μV ms μV/°C μV/montr μV pA |
| V- = 0V, Symbol V _{OS} TCV _{OS} IN OS R _{IND} | $V_{CM} = 2.5V, V_{O} = 2.5V \text{ and } R_{L} >$ $Parameter$ Input Offset Voltage (LMP2011 only) Input Offset Voltage (LMP2012 only) Offset Calibration Time Input Offset Voltage Long-Term Offset Drift Lifetime V _{OS} Drift Input Current Input Offset Current | 1MΩ. Boldface limits apply at the Conditions | e temperature extre Min | emes. Typ (Note 2) 0.12 0.12 0.12 0.5 0.015 0.006 2.5 -3 6 | Max (Note 3) 25 60 36 60 10 | Units μV ms μV/°C μV/month μV pA pA |
| V- = 0V, Symbol Vos TCV _{OS} IN OS RIND | $V_{CM} = 2.5V, V_{O} = 2.5V \text{ and } R_{L} >$ $Parameter$ Input Offset Voltage (LMP2011 only) Input Offset Voltage (LMP2012 only) Offset Calibration Time Input Offset Voltage Long-Term Offset Drift Lifetime V _{OS} Drift Input Current Input Offset Current Input Offset Current Input Differential Resistance | 1MΩ. Boldface limits apply at the | e temperature extra Min (Note 3) | Typ (Note 2) 0.12 0.12 0.12 0.5 0.0015 0.006 2.5 -3 6 9 | Max (Note 3) 25 60 36 60 10 | Units μV ms μV/°C μV/montr μV pA pA MΩ |
| V⁻ = 0V, | $V_{CM} = 2.5V, V_{O} = 2.5V \text{ and } R_{L} >$ $Parameter$ Input Offset Voltage (LMP2011 only) Input Offset Voltage (LMP2012 only) Offset Calibration Time Input Offset Voltage Long-Term Offset Drift Lifetime V _{OS} Drift Input Current Input Offset Current Input Offset Current Input Differential Resistance | 1MΩ. Boldface limits apply at the Conditions | e temperature extra Min (Note 3) | Typ (Note 2) 0.12 0.12 0.12 0.5 0.0015 0.006 2.5 -3 6 9 | Max (Note 3) 25 60 36 60 10 | Units μV ms μV/°C μV/montr μV pA pA MΩ |
| V- = 0V, Symbol V _{OS} TCV _{OS} IN OS RIND CMRR PSRR | $V_{CM} = 2.5V, V_{O} = 2.5V \text{ and } R_{L} >$ $Parameter$ Input Offset Voltage (LMP2011 only) Input Offset Voltage (LMP2012 only) Offset Calibration Time Input Offset Voltage Long-Term Offset Drift Lifetime V _{OS} Drift Input Current Input Offset Current Input Offset Current Common Mode Rejection Ratio | 1MΩ. Boldface limits apply at the Conditions | e temperature extra Min (Note 3) | emes. Typ (Note 2) 0.12 0.12 0.12 0.5 0.015 0.006 2.5 -3 6 9 130 | Max (Note 3) 25 60 36 60 10 | Units μV ms μV/°C μV/month μV pA pA MΩ dB |
| V- = 0V, Symbol V _{OS} TCV _{OS} I _{IN} I _{OS} R _{IND} CMRR | V $_{CM}$ = 2.5V, V_{O} = 2.5V and R_{L} >ParameterInput Offset Voltage (LMP2011 only)Input Offset Voltage (LMP2012 only)Offset Calibration TimeInput Offset Voltage Long-Term Offset DriftLifetime V $_{OS}$ DriftInput Offset CurrentInput Offset CurrentInput Offset CurrentInput Differential ResistanceCommon Mode Rejection RatioPower Supply Rejection Ratio | 1MΩ. Boldface limits apply at the Conditions $-0.3 \le V_{CM} \le 3.2$ $0 \le V_{CM} \le 3.2$ | e temperature extra (Note 3) (Note 3) | emes. Typ (Note 2) 0.12 0.12 0.5 0.015 0.006 2.5 -3 6 9 130 120 | Max (Note 3) 25 60 36 60 10 | Units μV ms μV/°C μV/month μV pA pA MΩ dB dB |
| V- = 0V, Symbol V _{OS} TCV _{OS} IN OS RIND CMRR PSRR | V $_{CM}$ = 2.5V, V_{O} = 2.5V and R_{L} >ParameterInput Offset Voltage (LMP2011 only)Input Offset Voltage (LMP2012 only)Offset Calibration TimeInput Offset Voltage Long-Term Offset DriftLifetime V $_{OS}$ DriftInput Offset CurrentInput Offset CurrentInput Offset CurrentInput Differential ResistanceCommon Mode Rejection RatioPower Supply Rejection Ratio | 1MΩ. Boldface limits apply at the Conditions $-0.3 \le V_{CM} \le 3.2$ $0 \le V_{CM} \le 3.2$ | e temperature extra (Note 3) (Note 3) | emes. Typ (Note 2) 0.12 0.12 0.5 0.015 0.006 2.5 -3 6 9 130 120 | Max (Note 3) 25 60 36 60 10 | Units μV ms μV/°C μV/month μV pA pA MΩ dB |

| Symbol | Parameter | Conditions | Min | Тур | Max | Units |
|----------------|----------------------------|---|----------|----------|----------|-------|
| | | | (Note 3) | (Note 2) | (Note 3) | |
| Vo | Output Swing | $R_L = 10 \text{ k}\Omega \text{ to } 2.5 \text{V}$ | 4.96 | 4.978 | | |
| | (LMP2011 only) | $V_{IN}(diff) = \pm 0.5V$ | 4.95 | | | v |
| | | | | 0.040 | 0.070 | v |
| | | | | | 0.085 | |
| | | $R_L = 2 k\Omega$ to 2.5V | 4.895 | 4.919 | | |
| | | $V_{IN}(diff) = \pm 0.5V$ | 4.875 | | | v |
| | | | | 0.091 | 0.115 | v |
| | | | | | 0.140 | |
| | Output Swing | $R_L = 10 \text{ k}\Omega \text{ to } 2.5 \text{V}$ | 4.92 | 4.978 | | |
| | (LMP2012 only) | $V_{IN}(diff) = \pm 0.5V$ | 4.91 | | | v |
| | | | | 0.040 | 0.080 | v |
| | | | | | 0.095 | |
| | | $R_L = 2 k\Omega$ to 2.5V | 4.875 | 4.919 | | |
| | | $V_{IN}(diff) = \pm 0.5V$ | 4.855 | | | v |
| | | | | 0.0.91 | 0.125 | v |
| | | | | | 0.150 | |
| I _o | Output Current | Sourcing, V _O = 0V | 8 | 15 | | |
| | | $V_{IN}(diff) = \pm 0.5V$ | 6 | | | |
| | | Sinking, $V_0 = 5V$ | 8 | 17 | | mA |
| | | $V_{IN}(diff) = \pm 0.5V$ | 6 | | | |
| Is | Supply Current per Channel | | | 0.930 | 1.20 | mA |
| 1 | | | | | | |

5V AC Electrical Characteristics $T_J = 25^{\circ}C$, $V^+ = 5V$, $V^- = 0V$, $V_{CM} = 2.5V$, $V_O = 2.5V$, and $R_L > 1M\Omega$. **Boldface** limits apply at the temperature extremes.

| Symbol | Parameter | Conditions | Min (Note 3) | Typ (Note 2) | Max (Note 3) | Units |
|--------------------|------------------------------|------------------------------------|-----------------|-----------------|-----------------|------------------|
| GBW | Gain-Bandwidth Product | | | 3 | | MHz |
| SR | Slew Rate | | | 4 | | V/µs |
| θ _m | Phase Margin | | | 60 | | deg |
| G _m | Gain Margin | | | -15 | | dB |
| e _n | Input-Referred Voltage Noise | | | 35 | | nV/√Hz |
| i _n | Input-Referred Current Noise | | | | | pA/√Hz |
| e _n p-p | Input-Referred Voltage Noise | R _S = 100Ω, DC to 10 Hz | | 850 | | nV _{pp} |
| t _{rec} | Input Overload Recovery Time | | | 50 | | ms |

1.50

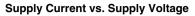
Note 1: Absolute Maximum Ratings indicate limits beyond which damage may occur. Operating Ratings indicate conditions for which the device is intended to be functional, but specific performance is not guaranteed. For guaranteed specifications and test conditions, see the Electrical Characteristics.

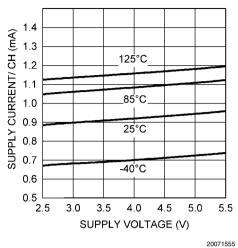
Note 2: Typical values represent the most likely parametric norm.

Note 3: Limits are 100% production tested at 25°C. Limits over the operating temperature range are guaranteed through correlations using statistical quality control (SQC) method.

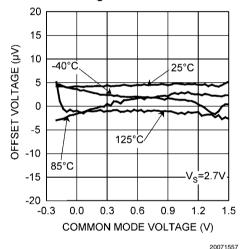
LMP2011 Single/LMP2012 Dual

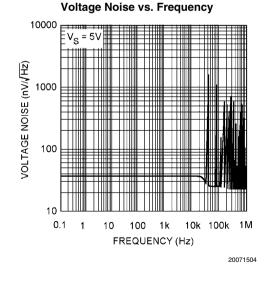
Typical Performance Characteristics $T_A=25C$, $V_S=5V$ unless otherwise specified.

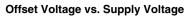


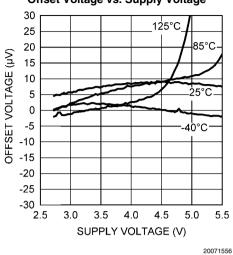


Offset Voltage vs. Common Mode

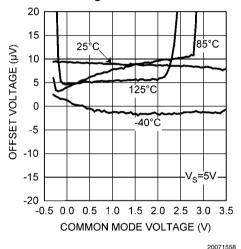




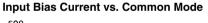


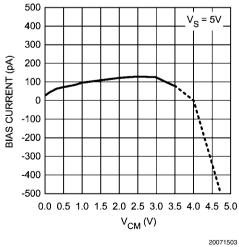


Offset Voltage vs. Common Mode

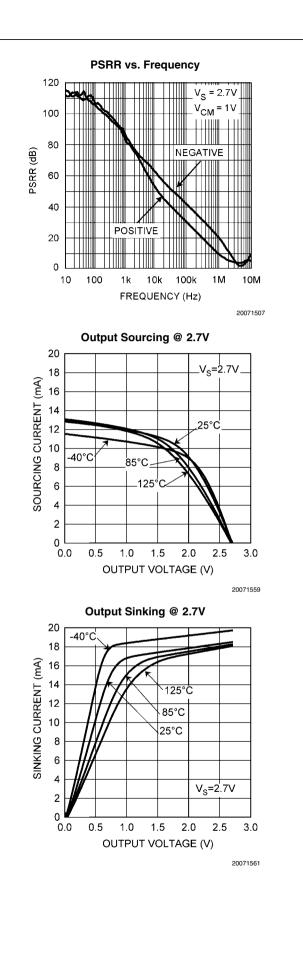


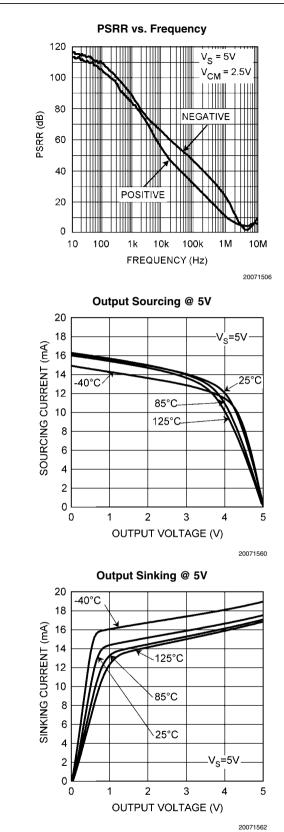
2007 1000



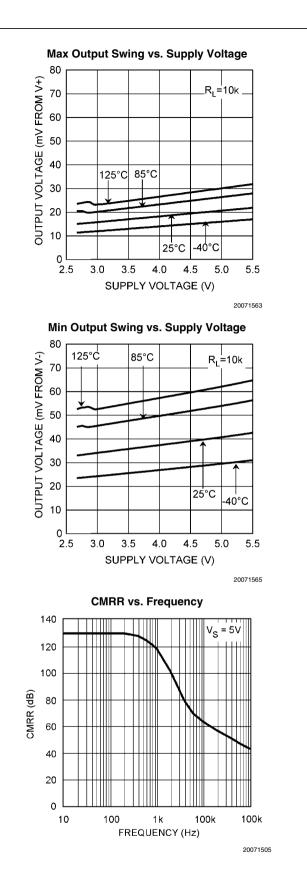


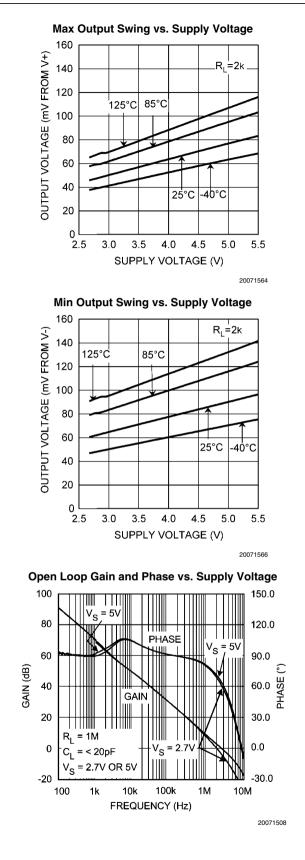




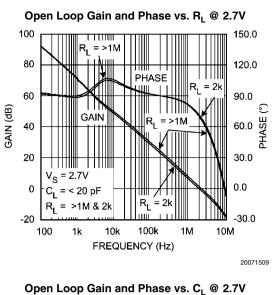


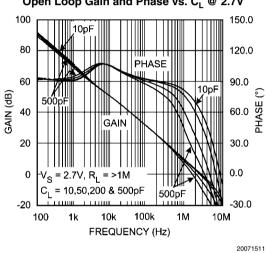




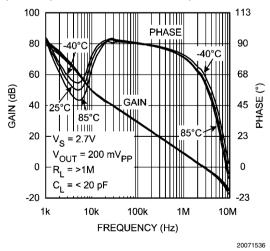


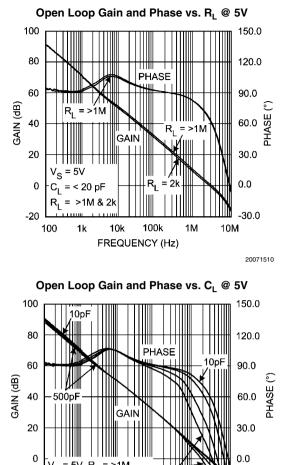






Open Loop Gain and Phase vs. Temperature @ 2.7V





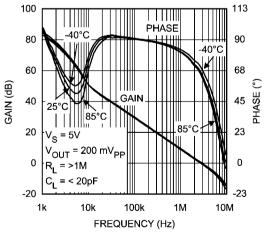
= 5V, R_L = >1M 's 500pF = 10,50,200 & 500pF -30.0 1k 10k 1M 10M 100k FREQUENCY (Hz) 20071512

Open Loop Gain and Phase vs. Temperature @ 5V

C.

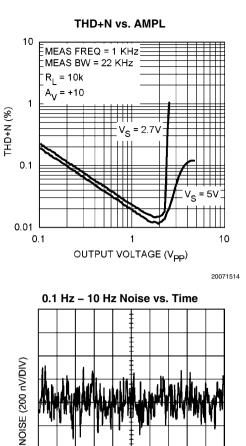
100

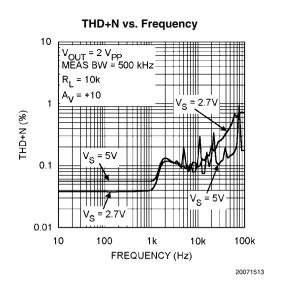
-20



20071537







1 sec/DIV

20071515

Application Information THE BENEFITS OF LMP201X NO 1/f NOISE

Using patented methods, the LMP201X eliminates the 1/f noise present in other amplifiers. That noise, which increases as frequency decreases, is a major source of measurement error in all DC-coupled measurements. Low-frequency noise appears as a constantly-changing signal in series with any measurement being made. As a result, even when the measurement is made rapidly, this constantly-changing noise signal will corrupt the result. The value of this noise signal can be surprisingly large. For example: If a conventional amplifier has a flat-band noise level of $10nV/\sqrt{Hz}$ and a noise corner of 10 Hz, the RMS noise at 0.001 Hz is $1\mu V/\sqrt{Hz}$. This is equivalent to a 0.50 µV peak-to-peak error, in the frequency range 0.001 Hz to 1.0 Hz. In a circuit with a gain of 1000, this produces a 0.50 mV peak-to-peak output error. This number of 0.001 Hz might appear unreasonably low, but when a data acquisition system is operating for 17 minutes, it has been on long enough to include this error. In this same time, the LM-P201X will only have a 0.21 mV output error. This is smaller by 2.4 x. Keep in mind that this 1/f error gets even larger at lower frequencies. At the extreme, many people try to reduce this error by integrating or taking several samples of the same signal. This is also doomed to failure because the 1/f nature of this noise means that taking longer samples just moves the measurement into lower frequencies where the noise level is even higher.

The LMP201X eliminates this source of error. The noise level is constant with frequency so that reducing the bandwidth reduces the errors caused by noise.

Another source of error that is rarely mentioned is the error voltage caused by the inadvertent thermocouples created when the common "Kovar type" IC package lead materials are soldered to a copper printed circuit board. These steel-based leadframe materials can produce over 35 μ V/°C when soldered onto a copper trace. This can result in thermocouple noise that is equal to the LMP201X noise when there is a temperature difference of only 0.0014°C between the lead and the board!

For this reason, the lead-frame of the LMP201X is made of copper. This results in equal and opposite junctions which cancel this effect. The extremely small size of the SOT-23 package results in the leads being very close together. This further reduces the probability of temperature differences and hence decreases thermal noise.

OVERLOAD RECOVERY

The LMP201X recovers from input overload much faster than most chopper-stabilized op amps. Recovery from driving the amplifier to 2X the full scale output, only requires about 40 ms. Many chopper-stabilized amplifiers will take from 250 ms to several seconds to recover from this same overload. This is because large capacitors are used to store the unadjusted offset voltage.

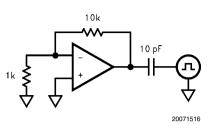


FIGURE 1. Overload Recovery Test

The wide bandwidth of the LMP201X enhances performance when it is used as an amplifier to drive loads that inject transients back into the output. ADCs (Analog-to-Digital Converters) and multiplexers are examples of this type of load. To simulate this type of load, a pulse generator producing a 1V peak square wave was connected to the output through a 10 pF capacitor. (*Figure 1*) The typical time for the output to recover to 1% of the applied pulse is 80 ns. To recover to 0.1% requires 860ns. This rapid recovery is due to the wide bandwidth of the output stage and large total GBW.

NO EXTERNAL CAPACITORS REQUIRED

The LMP201X does not need external capacitors. This eliminates the problems caused by capacitor leakage and dielectric absorption, which can cause delays of several seconds from turn-on until the amplifier's error has settled.

MORE BENEFITS

The LMP201X offers the benefits mentioned above and more. It has a rail-to-rail output and consumes only 950 μ A of supply current while providing excellent DC and AC electrical performance. In DC performance, the LMP201X achieves 130 dB of CMRR, 120 dB of PSRR and 130 dB of open loop gain. In AC performance, the LMP201X provides 3 MHz of gainbandwidth product and 4 V/ μ s of slew rate.

HOW THE LMP201X WORKS

The LMP201X uses new, patented techniques to achieve the high DC accuracy traditionally associated with chopper-stabilized amplifiers without the major drawbacks produced by chopping. The LMP201X continuously monitors the input offset and corrects this error. The conventional chopping process produces many mixing products, both sums and differences, between the chopping frequency and the incoming signal frequency. This mixing causes large amounts of distortion, particularly when the signal frequency approaches the chopping frequency. Even without an incoming signal, the chopper harmonics mix with each other to produce even more trash. If this sounds unlikely or difficult to understand, look at the plot (Figure 2), of the output of a typical (MAX432) chopper-stabilized op amp. This is the output when there is no incoming signal, just the amplifier in a gain of -10 with the input grounded. The chopper is operating at about 150 Hz; the rest is mixing products. Add an input signal and the noise gets much worse. Compare this plot with Figure 3 of the LMP201X. This data was taken under the exact same conditions. The auto-zero action is visible at about 30 kHz but note the absence of mixing products at other frequencies. As a result, the LMP201X has very low distortion of 0.02% and very low mixing products.

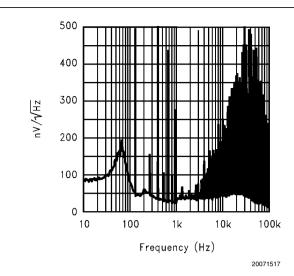


FIGURE 2. The Output of a Chopper Stabilized Op Amp (MAX432)

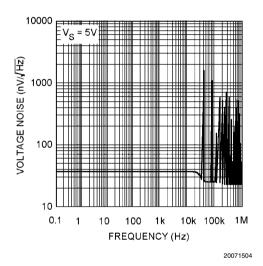


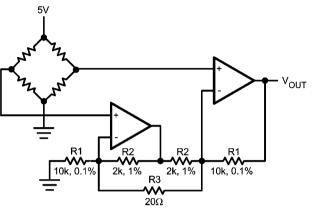
FIGURE 3. The Output of the LMP2011/LMP2012

INPUT CURRENTS

The LMP201X's input currents are different than standard bipolar or CMOS input currents in that it appears as a current flowing in one input and out the other. Under most operating conditions, these currents are in the picoamp level and will have little or no effect in most circuits. These currents tend to increase slightly when the common-mode voltage is near the minus supply. (See the typical curves.) At high temperatures such as 85°C, the input currents become larger, 0.5 nA typical, and are both positive except when the V_{CM} is near V⁻. If operation is expected at low common-mode voltages and high temperature, do not add resistance in series with the inputs to balance the impedances. Doing this can cause an increase in offset voltage. A small resistance such as 1 k Ω can provide some protection against very large transients or overloads, and will not increase the offset significantly.

PRECISION STRAIN-GAUGE AMPLIFIER

This Strain-Gauge amplifier (*Figure 4*) provides high gain (1006 or ~60 dB) with very low offset and drift. Using the resistors' tolerances as shown, the worst case CMRR will be greater than 108 dB. The CMRR is directly related to the resistor mismatch. The rejection of common-mode error, at the output, is independent of the differential gain, which is set by R3. The CMRR is further improved, if the resistor ratio matching is improved, by specifying tighter-tolerance resistors, or by trimming.



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FIGURE 4. Precision Strain Gauge Amplifier

Extending Supply Voltages and Output Swing by Using a Composite Amplifier Configuration:

In cases where substantially higher output swing is required with higher supply voltages, arrangements like the ones shown in Figure 5 and Figure 6 could be used. These configurations utilize the excellent DC performance of the LMP201X while at the same time allow the superior voltage and frequency capabilities of the LM6171 to set the dynamic performance of the overall amplifier. For example, it is possible to achieve ±12V output swing with 300 MHz of overall GBW $(A_{V} = 100)$ while keeping the worst case output shift due to V_{OS} less than 4 mV. The LMP201X output voltage is kept at about mid-point of its overall supply voltage, and its input common mode voltage range allows the V- terminal to be grounded in one case (Figure 5, inverting operation) and tied to a small non-critical negative bias in another (Figure 6, noninverting operation). Higher closed-loop gains are also possible with a corresponding reduction in realizable bandwidth. Table 1 shows some other closed loop gain possibilities along with the measured performance in each case.

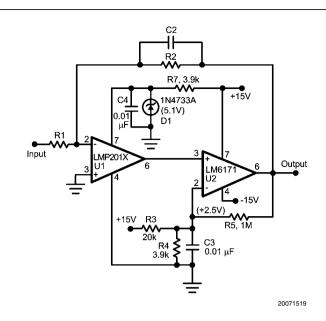


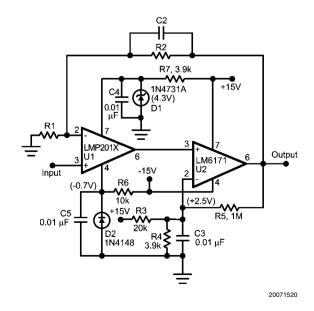
FIGURE 5. Composite Amplifier Configuration

| A _V | R1 | R2 | C2 | BW | SR | en p-p |
|----------------|-----|------|------|-------|--------|---------------------|
| | (Ω) | (Ω) | (pF) | (MHz) | (V/µs) | (mV _{PP}) |
| 50 | 200 | 10k | 8 | 3.3 | 178 | 37 |
| 100 | 100 | 10k | 10 | 2.5 | 174 | 70 |
| 100 | 1k | 100k | 0.67 | 3.1 | 170 | 70 |
| 500 | 200 | 100k | 1.75 | 1.4 | 96 | 250 |
| 1000 | 100 | 100k | 2.2 | 0.98 | 64 | 400 |

| TABLE 1. Composite Amplifier Measured Performance |
|---|
|---|

In terms of the measured output peak-to-peak noise, the following relationship holds between output noise voltage, $e_n p_p$, for different closed-loop gain, A_V , settings, where -3 dB Bandwidth is BW:

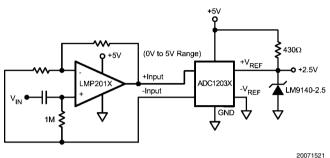
$$\frac{e_{npp1}}{e_{npp2}} = \sqrt{\frac{BW1}{BW2}} \bullet \frac{A_V1}{A_V2}$$
(1)





It should be kept in mind that in order to minimize the output noise voltage for a given closed-loop gain setting, one could minimize the overall bandwidth. As can be seen from Equation 1 above, the output noise has a square-root relationship to the Bandwidth.

In the case of the inverting configuration, it is also possible to increase the input impedance of the overall amplifier, by raising the value of R1, without having to increase the feed-back resistor, R2, to impractical values, by utilizing a "Tee" network as feedback. See the LMC6442 data sheet (Application Notes section) for more details on this.



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FIGURE 7. AC Coupled ADC Driver

LMP201X AS ADC INPUT AMPLIFIER

The LMP201X is a great choice for an amplifier stage immediately before the input of an ADC (Analog-to-Digital Converter), whether AC or DC coupled. See *Figure 7* and *Figure* 8. This is because of the following important characteristics:

- A) Very low offset voltage and offset voltage drift over time and temperature allow a high closed-loop gain setting without introducing any short-term or long-term errors. For example, when set to a closed-loop gain of 100 as the analog input amplifier for a 12-bit A/D converter, the overall conversion error over full operation temperature and 30 years life of the part (operating at 50°C) would be less than 5 LSBs.
- B) Fast large-signal settling time to 0.01% of final value (1.4 μ s) allows 12 bit accuracy at 100 KH_Z or more sampling rate.
- **C)** No flicker (1/f) noise means unsurpassed data accuracy over any measurement period of time, no matter how long. Consider the following op amp performance, based on a typical low-noise, high-performance commercially-available device, for comparison:

Op amp flatband noise = 8nV/√Hz

1/f corner frequency = 100 Hz

$$A_{V} = 2000$$

Measurement time = 100 sec

Bandwidth = 2 Hz

This example will result in about 2.2 mV_{PP} (1.9 LSB) of output noise contribution due to the op amp alone, compared to about 594 μ V_{PP} (less than 0.5 LSB) when that op amp is replaced with the LMP201X which has no 1/f contribution. If the measurement time is increased from 100 seconds to 1 hour, the improvement realized by using the LMP201X would be a factor of about 4.8 times (2.86 mV_{PP} compared to 596 μ V when LMP201X is used) mainly because the LMP201X accuracy is not compromised by increasing the observation time.

D) Copper leadframe construction minimizes any thermocouple effects which would degrade low level/high gain data conversion application accuracy (see discussion under "The Benefits of the LMP201X" section above).

E) Rail-to-Rail output swing maximizes the ADC dynamic range in 5-Volt single-supply converter applications. Below are some typical block diagrams showing the LM-P201X used as an ADC amplifier (*Figure 7* and *Figure 8*).

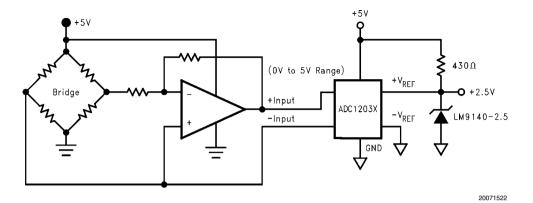
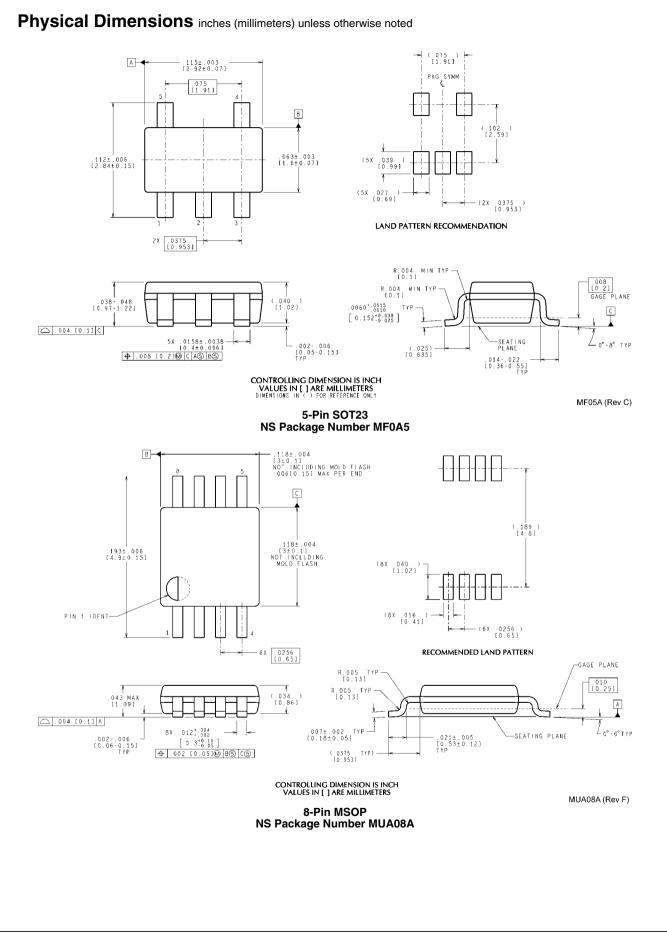
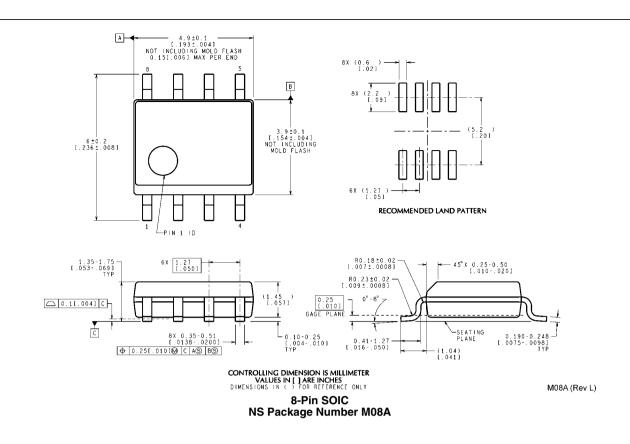


FIGURE 8. DC Coupled ADC Driver

LMP2011 Single/LMP2012 Dual







Notes

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